



**ESWAR COLLEGE OF ENGINEERING:
NARASARAOPET**

Approved by AICTE, New Delhi., Affiliated to JNTUK, Kakinada
Kesanupalli Village, Narasaraopet – 522 601,
Palnadu Dist. A.P.

Phone No. 9121214708

Email ID: principal@eswarcollegeofengg.org, eswarcollegeofengg@gmail.com
web:eswarcollegeofengg.org

Department of Electronics and Communication Engineering

21-01-2019

To
The Principal
Eswar College of Engineering
Narasaraopet

Through HOD-ECE

From
B Bhavani
Assistant Professor
Faculty Coordinator

Sub: Requesting for permission to conduct a value-added course on “ Microelectronics Devices from 04-02-2019 to 08-02-2019”.

Dear Sir,

The Department of ECE is planning to organize a 1-week value-added course on “Microelectronics Devices” from 04-02-2019 to 08-02-2019.

Total Number of Students registered: 102 No's (III B.Tech II Sem ECE-A and B).

Resource Person: **SK Jilani Noor Basha**, Assistant Professor,
Department of ECE, RISE Institute of Gandhi,
Ongole

Certificate Criteria: 60% of marks in Evaluation, 80% of attendance

In connection with the programme, we request your approval to organize the same and to make the programme a grand success.

Thanks and regards,

Name:, B Bhavani

Signature *Bha*

.....*B. BHAVANI*.....

HOD- Comments

please consider

K Jilani Noor Basha
Department of ECE
Eswar College of Engineering
Kesanupalli (V), Narasaraopet - 522 601.

Principal Comments: *Recommended*

Approved/ Rejected

[Signature]
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NARASARAOPET-522 601, Guntur (Dt.)

[Signature]
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ESWAR COLLEGE OF ENGINEERING
NARASARAOPET-522 601, Guntur (Dt.)

Date: 28-01-2019

CIRCULAR

All B.Tech III/II ECE students are hereby notified that a value added course titled "Microelectronics:Devices" will be conducted from 04-02-2019 to 08-02-2019. It is mandatory for all students to enroll their names with course co-ordination Sk Lal John Basha, Assistant Professor, Department of ECE.

Copy to:

1. A.O.B
3. Library *SKL*
5. HOD's

Civil - *SKL*
ECE - *SKL*
CSE - *SKL*
SSH - *SKL*

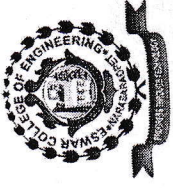
ECE - *SKL*

SKL
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NARASARAOPET-522 001, Guntur (Dist)
SKL

2. Accounts
4. Exam Cell - *SKL*

Class Rooms:

211 *SKL* 212 *SKL* 213 *SKL* 110 *SKL*
237 *SKL* 232 *SKL* 113- *SKL*
236 *SKL* 235 *SKL* 214 *SKL*



**ONE WEEK ADD-ON COURSE
MICROELECTRONICS DEVICES**
Organized by
**DEPARTMENT OF ELECTRONICS
AND COMMUNICATION
ENGINEERING,
ESWAR COLLEGE OF
ENGINEERING**

Kesanupalli (V), Narasaraopet
on

04-02-2019 to 08-02-2019

Registration Form

Name _____

Department: _____

Contact No.: _____

E-mail: _____

Course Content

- Introduction to Microelectronics
- Semiconductor Diodes
- Bipolar Junction Transistors (BJT)
- Field-Effect Transistors (FET)
- Integrated Circuits and Future Trends

Resource Person

SK Jilani Noor Basha, Assistant Professor,
Department of ECE, RISE Institute of
Gandhi, Ongole

Eligibility:

This course is intended for IV B.Tech I
Sem ECE

Scheduled date

04-02-2019 to 08-02-2019

Last date For Receipt of Application

02-02-2019.

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Objectives:

- To provide participants with a comprehensive understanding of the fundamental principles, operation, and applications of microelectronic devices.
- To equip participants with practical skills in analyzing and designing microelectronic circuits and systems, enhancing their ability to implement and troubleshoot electronic devices.
- To foster critical thinking and problem-solving abilities by exploring advanced topics in microelectronics, such as integrated circuits, emerging technologies, and their impact on modern electronic systems

Outcomes

- Participants will gain a comprehensive understanding of microelectronics principles, including semiconductor materials, diodes, and transistors.
- Participants will develop practical skills in analyzing, designing, and implementing microelectronic circuits and systems, enhancing their hands-on experience.
- Participants will explore advanced topics in microelectronics, such as integrated circuits (ICs), field-effect transistors (FETs), and emerging nanoelectronic technologies..
- Participants will demonstrate proficiency in applying microelectronics knowledge to solve real-world engineering problems and challenges.

About college

Eswar College of Engineering was established during the academic year 2008 -09 and sponsored by Shalk Dada Sahab Charitable Trust, with a vision of Imparting futuristic technical education and instill high patterns of discipline in order to set global standards and making the students technologically superior and ethically strong. The young and dynamic promoters have selected this rural area with lot of foresight. The Institution is spread over 22 acres of lush green landscape and located at 5th km stone on the Narasaraopet- Chitalkulurpet Road. The Institution offers the UG Courses B.Tech-CIVIL, EEE, ECE, CSE, AME, ME, PG Courses M.Tech-PE&ED, DECS, CSE, CAD/CAM & MBA. The tourist places near by are Kotappakonda, Amaravathi, Suryanka Beach. Eswar College of Engineering is having MOU with International Institute of Information Technology IIT-Hyderabad and introduced CIT Programme for students Digital Class facility is also provided in association with Manipal K12, Bangalore. the very first college in Andhra Pradesh

About department

The Department of Electronics & Communication Engineering came into existence in 2001 immediately when the Institute was founded. It started with an intake of 60 students which was subsequently raised to 120 over a period of time. It offers 4 year B.Tech degree program in Electronics & Communication Engineering, 2 Year M.Tech degree in Digital Electronics and Communication system with an intake of 18.

Vision: To excel in the emerging fields of electronics and communication engineering by conducting cutting-edge research, advocating for ethical principles, and addressing societal needs

Mission:

- To provide strong fundamentals and technical skills through effective teaching learning Methodologies, disseminate knowledge by organizing seminars, field visits and workshops.
- To provide an ambience for research through collaborations with industry and academia.
- To develop responsible citizens and professional leaders with high ethical and moral values, who contribute in

CHIEF PATRONS

SRI.SHAIK.MEERAVALLI

Chairman

SRI.SHAIK.KAREEM MOHIDDIN

Secretary & Correspondent

SRI.SHAIK MASTHAN SHARIF

Managing Director

PATRON

DR.G. NAGA MALLESWARA RAO

Principal

Convener

Dr SK Mirza Shafi shahasavar,

HOD-ECE Department,

The Co-Ordinator,

ONE WEEK ADD-ON COURSE

MICROELECTRONICS DEVICES

ESWAR COLLEGE OF ENGINEERING,

KESANUPALLI (V),

NARASARAOPET (M),

GUNTUR-DT

Ph.No: 8985793922, 9581741110

E-mail: www.eswarcollegeofengg.org

www.eswarcollegeofengg.blogspot.com

Declaration:

The above is formation is true to the best of my knowledge. I agree to abide by the rules and regulations governing the course. If selected I shall attend the course for the entire the duration. I also under take the responsibilities to inform the coordinator in case I am unable to attend the course

Place:

Date:

Signature of the applicant

Sponsorship certificate:

Mr/ Mrs./

Dr.....

Is an employee of our institute/
organization and is here by sponsored and
organization will be permitted to attend the course, if

selected

Place

Date



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Department of Electronics and Communication Engineering

Course Name: Microelectronics Devices

Proposed Syllabus

Day 1: Introduction to Microelectronics

Basics of Microelectronics, Definition, history, and importance, Overview of microelectronic devices and their applications, Semiconductor Materials, Types of semiconductors: intrinsic and extrinsic, Semiconductor doping and carrier concentrations

Day 2: Semiconductor Diodes

PN Junction Diode, Principle of operation, I-V characteristics, Applications: rectifiers, clippers, and clampers, Special Diodes, Zener diode, Schottky diode, LED, and photodiode, Characteristics and applications

Day 3: Bipolar Junction Transistors (BJT)

Basics of BJT, Principle of operation, modes of operation, BJT characteristics: alpha, beta, and V-I curves, BJT Amplifiers and Switching Circuits, Common emitter, common base, and common collector configurations, Applications in amplifiers and digital circuits

Day 4: Field-Effect Transistors (FET)

Basics of FET, Principle of operation: JFET and MOSFET, FET characteristics and I-V curves, FET Amplifiers and Applications, Common source, common drain, and common gate configurations, Applications in amplifiers, switches, and integrated circuits

Day 5: Integrated Circuits and Future Trends

Basics of Integrated Circuits (ICs), Types of ICs: analog, digital, and mixed-signal, IC fabrication techniques: CMOS, BiCMOS, Emerging Trends in Microelectronics, Nanoelectronics, MEMS, and quantum devices, Future prospects and research opportunities

CO Statements

CO's	CO Statements
CO1	Participants will gain a comprehensive understanding of microelectronics principles, including semiconductor materials, diodes, and transistors.
CO2	Participants will develop practical skills in analyzing, designing, and implementing microelectronic circuits and systems, enhancing their hands-on experience.
CO3	Participants will explore advanced topics in microelectronics, such as integrated circuits (ICs), field-effect transistors (FETs), and emerging nanoelectronic technologies..
CO4	Participants will demonstrate proficiency in applying microelectronics knowledge to solve real-world engineering problems and challenges.
CO5	Participants will collaborate on group projects to design and prototype innovative microelectronic devices, fostering teamwork and innovation skills.


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Department of Electronics and Communication Engineering

Feedback form

Course Name: Microelectronics Devices


Please place tick marks at the respective column

S.No	Particulars	Excellent	Very good	Good	Average	Poor
1	How well did you achieve this learning goal in this course?	✓				
2	Does the course contain meet the expectation?		✓			
3	Is The lecture sequence was well planned	✓				
4	Does the Lecture content illustrate with adequate examples		✓			
5	Do you Level of the course up to the standards?	✓				
6	Does the Course meets the level of new knowledge	✓				
7	Is th lecture clear and easy to understand?	✓				
8	Did your expect Teaching aids are effectively used?	✓				
9	Does the resource person interacted well and cleared the doubts.	✓				
10	Overall organization of the course		✓			

Comments

1. Basics of microelectronics are explained very well
2. Over view of different diodes understand


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Signature of the student



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Department of Electronics and Communication Engineering Feedback form


Course Name: Microelectronics Devices

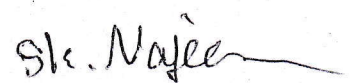
Please place tick marks at the respective column

S.No	Particulars	Excellent	Very good	Good	Average	Poor
1	How well did you achieve this learning goal in this course?	✓				
2	Does the course contain meet the expectation?	✓				
3	Is The lecture sequence was well planned	✓				
4	Does the Lecture content illustrate with adequate examples	✓				
5	Do you Level of the course up to the standards?		✓			
6	Does the Course meets the level of new knowledge		✓			
7	Is th lecture clear and easy to understand?		✓			
8	Did your expect Teaching aids are effectively used?		✓			
9	Does the resource person interacted well and cleared the doubts.		✓			
10	Overall organization of the course		✓			

Comments

1. Operation of RTT understood clearly
2. Basic Things of FET is explained well


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Signature of the student



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Department of Electronics and Communication Engineering

Feedback form

Course Name: Microelectronics Devices

Please place tick marks at the respective column

S.No	Particulars	Excellent	Very good	Good	Average	Poor
1	How well did you achieve this learning goal in this course?	✓				
2	Does the course contain meet the expectation?		✓			
3	Is The lecture sequence was well planned	✓				
4	Does the Lecture content illustrate with adequate examples		✓			
5	Do you Level of the course up to the standards?	✓				
6	Does the Course meets the level of new knowledge	✓				
7	Is th lecture clear and easy to understand?		✓			
8	Did your expect Teaching aids are effectively used?		✓			
9	Does the resource person interacted well and cleared the doubts.		✓			
10	Overall organization of the course	✓				

Comments

1. Brief Explain about Jcb is understand
2. Trends in micro electronics is explained way

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H. S. Sankar
Signature of the student



Phone No.
9121214708

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Department of Electronics and Communication Engineering

Feedback Analysis

Course Name: MICROELECTRONICS DEVICES

Number of students attended/ given feedback 102

S.No	Particulars	Excellent	Very good	Good	Average	Poor	levels
1	How well did you achieve this learning goal in this course?	62	20	18	1	1	0.84559
2	The course contain meet the expectation	64	22	10	5	1	0.85049
3	The lecture sequence was well planned	63	20	16	2	1	0.84804
4	Lecture content illustrated with adequate examples	62	20	17	2	1	0.84314
5	Level of the course up to the mark?	66	20	13	2	1	0.86275
6	Course highlights the level of new knowledge	65	30	4	2	1	0.88235
7	The lecture was clear and easy to understand?	62	21	12	5	2	0.83333
8	Teaching aids are effectively used?	61	20	18	2	1	0.83824
9	The resource person interacted well and cleared the doubts.	66	12	22	2		0.84804
10	Overall organization of the course	70	20	4	5	3	0.8652
							0.85172

Bhar

Over all feedback value :

3.406862745

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Department of Electronics and Communication Engineering

Course Name: Microelectronics Devices

Evaluation of the Value-Added Courses

Answer all the Questions Each Question Carry 1 Mark

Total Marks: 20M


Min Marks: 12 Marks

Name of the Student

H.T.No:

Marks obtained:

1. What is the primary function of a PN junction diode? []
A) Signal amplification **B) Rectification** C) Switching D) Oscillation
2. Which semiconductor material is used in an N-type semiconductor? []
A) Silicon B) Germanium C) Boron **D) Phosphorus**
3. What does BJT stand for? []
A) Bipolar Junction Transistor B) Bi-directional Junction Transistor
C) Binary Junction Transistor D) Base-Junction Transistor
4. What type of diode is used as a voltage regulator? []
A) Zener diode B) LED C) Photodiode D) Schottky diode
5. Which FET configuration has the highest input impedance? []
A) Common source B) Common drain **C) Common gate** D) Common collector
6. What is the main advantage of CMOS technology over other IC fabrication techniques? []
A) Higher speed **B) Lower power consumption** C) Larger die size D) Higher cost
7. What is the primary purpose of a photodiode? []
A) Emit light **B) Detect light** C) Amplify signals D) Store data
8. Which semiconductor device acts as a current-controlled device? []
A) Diode **B) BJT** C) MOSFET D) Zener diode
9. What is the main function of a capacitor in a rectifier circuit? []
A) Voltage regulation B) Current amplification
C) Energy storage **D) Signal filtering**
10. What is the main principle behind the operation of a JFET? []
A) Bipolar junction **B) Field effect** C) Avalanche breakdown D) Tunneling effect
11. Which type of diode has a forward-biased voltage drop of approximately 0.7V? []
A) Zener diode B) Schottky diode **C) LED** D) Photodiode


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12. What does MOSFET stand for? []
A) Metal-Oxide Semiconductor Field-Effect Transistor **B) Mono-Oxide Silicon Field-Effect Transistor**
C) Metal-Silicon Field-Effect Transistor D) Mono-Silicon Oxide Transistor
13. Which semiconductor device is used for switching applications due to its fast switching speed?
A) LED B) BJT **C) IGBT** D) Zener diode []
14. What is the primary function of an operational amplifier (Op-Amp) in microelectronic circuits?
A) Voltage amplification B) Current amplification []
C) Power amplification D) Energy storage
15. What is the main advantage of using a Schottky diode compared to a standard PN junction diode? []
A) Lower forward voltage drop B) Higher breakdown voltage
C) Faster switching speed D) Larger capacitance
16. Which of the following is NOT a type of semiconductor material? []
A) Silicon B) Germanium **C) Copper** D) Gallium arsenide
17. What is the primary function of a capacitor in a microelectronic circuit? []
A) Energy conversion B) Voltage regulation **C) Signal storage** D) Current amplification
18. Which semiconductor device is commonly used as a voltage-controlled oscillator (VCO)? []
A) BJT B) FET C) Schottky diode **D) Varactor diode**
19. What is the main advantage of using a MEMS-based sensor over traditional sensors? []
A) Higher cost B) Larger size C) Lower power consumption **D) Mechanical flexibility**
20. Which of the following materials is commonly used as an insulator in semiconductor devices? []
A) Silicon B) Copper **C) Glass** D) Aluminum


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web:eswarcollegeofengg.org

Department of Electronics and Communication Engineering

Course Name: Microelectronics Devices
Evaluation of the Value-Added Courses

Answer all the Questions Each Question Carry 1 Mark

Total Marks: 20M

Min Marks: 12 Marks

Name of the Student G. ARUN H.T.No: 16SC1A0408 Marks obtained: 16

1. What is the primary function of a PN junction diode? [B]
A) Signal amplification B) Rectification C) Switching D) Oscillation
2. Which semiconductor material is used in an N-type semiconductor? [D]
A) Silicon B) Germanium C) Boron D) Phosphorus
3. What does BJT stand for? [B]
A) Bipolar Junction Transistor B) Bi-directional Junction Transistor
C) Binary Junction Transistor D) Base-Junction Transistor
4. What type of diode is used as a voltage regulator? [Z]
A) Zener diode B) LED C) Photodiode D) Schottky diode
5. Which FET configuration has the highest input impedance? [B]
A) Common source B) Common drain C) Common gate D) Common collector
6. What is the main advantage of CMOS technology over other IC fabrication techniques? [R]
A) Higher speed B) Lower power consumption C) Larger die size D) Higher cost
7. What is the primary purpose of a photodiode? [B]
A) Emit light B) Detect light C) Amplify signals D) Store data
8. Which semiconductor device acts as a current-controlled device? [B]
A) Diode B) BJT C) MOSFET D) Zener diode
9. What is the main function of a capacitor in a rectifier circuit? [D]
A) Voltage regulation B) Current amplification
C) Energy storage D) Signal filtering
10. What is the main principle behind the operation of a JFET? [D]
A) Bipolar junction B) Field effect C) Avalanche breakdown D) Tunneling effect
11. Which type of diode has a forward-biased voltage drop of approximately 0.7V? [B]
A) Zener diode B) Schottky diode C) LED D) Photodiode


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12. What does MOSFET stand for?

[B]

- A) Metal-Oxide Semiconductor Field-Effect Transistor B) Mono-Oxide Silicon Field-Effect Transistor
C) Metal-Silicon Field-Effect Transistor D) Mono-Silicon Oxide Transistor

13. Which semiconductor device is used for switching applications due to its fast switching speed?

- A) LED B) BJT C) IGBT D) Zener diode

[C]

14. What is the primary function of an operational amplifier (Op-Amp) in microelectronic circuits?

- A) Voltage amplification B) Current amplification
C) Power amplification D) Energy storage

[A]

15. What is the main advantage of using a Schottky diode compared to a standard PN junction diode?

[C]

- A) Lower forward voltage drop B) Higher breakdown voltage
C) Faster switching speed D) Larger capacitance

16. Which of the following is NOT a type of semiconductor material?

[C]

- A) Silicon B) Germanium C) Copper D) Gallium arsenide

17. What is the primary function of a capacitor in a microelectronic circuit?

[C]

- A) Energy conversion B) Voltage regulation C) Signal storage D) Current amplification

18. Which semiconductor device is commonly used as a voltage-controlled oscillator (VCO)?

[D]

- A) BJT B) FET C) Schottky diode D) Varactor diode

19. What is the main advantage of using a MEMS-based sensor over traditional sensors?

[D]

- A) Higher cost B) Larger size C) Lower power consumption D) Mechanical flexibility

20. Which of the following materials is commonly used as an insulator in semiconductor devices?

- A) Silicon B) Copper C) Glass D) Aluminum

[C]





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Department of Electronics and Communication Engineering

Course Name: Microelectronics Devices

Evaluation of the Value-Added Courses

Answer all the Questions Each Question Carry 1 Mark

Total Marks: 20M

Min Marks: 12 Marks

Name of the Student B. ESWAR **H.T.No:** 16JEA140 **Marks obtained:** 13

- 415
1. What is the primary function of a PN junction diode? [B]
A) Signal amplification B) Rectification C) Switching D) Oscillation
 2. Which semiconductor material is used in an N-type semiconductor? [D]
A) Silicon B) Germanium C) Boron D) Phosphorus
 3. What does BJT stand for? [B]
A) Bipolar Junction Transistor B) Bi-directional Junction Transistor
C) Binary Junction Transistor D) Base-Junction Transistor
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A) Zener diode B) Schottky diode C) LED D) Photodiode

ESWAR COLLEGE OF ENGINEERING
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12. What does MOSFET stand for?

- A) Metal-Oxide Semiconductor Field-Effect Transistor B) Mono-Oxide Silicon Field-Effect Transistor
C) Metal-Silicon Field-Effect Transistor D) Mono-Silicon Oxide Transistor

[B]

13. Which semiconductor device is used for switching applications due to its fast switching speed?

- A) LED B) BJT C) IGBT D) Zener diode

[C]

14. What is the primary function of an operational amplifier (Op-Amp) in microelectronic circuits?

- A) Voltage amplification B) Current amplification
C) Power amplification D) Energy storage

[A]

15. What is the main advantage of using a Schottky diode compared to a standard PN junction diode?

- A) Lower forward voltage drop B) Higher breakdown voltage
C) Faster switching speed D) Larger capacitance

[C]

16. Which of the following is NOT a type of semiconductor material?

- A) Silicon B) Germanium C) Copper D) Gallium arsenide

[C]

17. What is the primary function of a capacitor in a microelectronic circuit?

- A) Energy conversion B) Voltage regulation C) Signal storage D) Current amplification

[C]

18. Which semiconductor device is commonly used as a voltage-controlled oscillator (VCO)?

- A) BJT B) FET C) Schottky diode D) Varactor diode

[D]

19. What is the main advantage of using a MEMS-based sensor over traditional sensors?

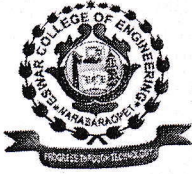
- A) Higher cost B) Larger size C) Lower power consumption D) Mechanical flexibility

[C]

20. Which of the following materials is commonly used as an insulator in semiconductor devices?

- A) Silicon B) Copper C) Glass D) Aluminum

[C]



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Department of Electronics and Communication Engineering

Marks Sheet

1 Week Add-On Course on “Microelectronics Devices”

Dates: 04-02-2019 to 08-02-2019.

S.No	H.T.No	Name of the Student Signature	Marks
1	16JE1A0401	DASARI ADI LAKSHMI	13
2	16JE1A0402	DEMULA ALEKHIA	13
3	16JE1A0403	THUMU ANURADHA	14
4	16JE1A0404	KOMMU ANUSHA	15
5	16JE1A0405	CHERUKULA ANUSHA	16
6	16JE1A0406	GUNDA ARUN KUMAR	16
7	16JE1A0407	TAPPETLA ASWANI	17
8	16JE1A0408	KANDULA BALA NAGENDRA KUMAR	19
9	16JE1A0409	CHINTA BHAVANI	13
10	16JE1A0410	BATTULA BHAVANI	14
11	16JE1A0411	SHAIK BIKARI	15
12	16JE1A0412	MUNTHA DEEPTHI	13
13	16JE1A0413	LOYA DHANA SEKHAR	16
14	16JE1A0414	ORSU DURGA PRASAD	18
15	16JE1A0415	BANDI ESWAR	15
16	16JE1A0416	MAILA ESWARAMMA	16
17	16JE1A0417	ALURI GANESH	17
18	16JE1A0418	PALEPU GAYATHRI	17
19	16JE1A0419	UPPALAPATI GEETHA PAVANI	18
20	16JE1A0420	SIVADI GOPI	13
21	16JE1A0422	DUDDU HEMA SRI	14
22	16JE1A0423	SHAIK IZADBASHA	13
23	16JE1A0424	JAFRIN SHAIK	14
24	16JE1A0425	GANAPAVARAPU JAN BABU	13
25	16JE1A0426	SK JANI BASHA	15
26	16JE1A0427	MAKKENA JAYAPPAUL	15
27	16JE1A0428	DARGA JHONY SHAHID	16
28	16JE1A0430	SHAIK KANDIPATI JAN SAIDA	15

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29	16JE1A0431	SHAIK KARIMULLA	12
30	16JE1A0432	SYED KARISHMA KAREEM	12
31	16JE1A0433	PATAN KHAJA VALI	13
32	16JE1A0434	SINDIRI LAKSHMI MANASA	14
33	16JE1A0436	THOTAPALLI LAKSHMI PATHI	15
34	16JE1A0437	SEKHAR LALITHA	16
35	16JE1A0439	DAVULURI LEELE UMAMAHESWARA RAO	15
36	16JE1A0440	MUKKADALA LENIN	16
37	16JE1A0441	BOBBALA MADHURI	13
38	16JE1A0443	KOTHA MANOJ KUMAR	13
39	16JE1A0444	MEGHAVATHU MEENAKSHI MANI BAI	14
40	16JE1A0445	SYED MIRSHAD	13
41	16JE1A0446	SHAIK MOHAMMAD VALI	14
42	16JE1A0447	SHAIK MUBEEN KOUSAR	16
43	16JE1A0448	SHAIK NADIYA	16
44	16JE1A0450	MENTHULA NAGA LAKSHMI	15
45	16JE1A0451	ADDANKI NAGA TRIVENI	13
46	16JE1A0452	POLISETTY NAGA VENKATA MOHANA SAI SESANK	13
47	16JE1A0453	LINGALA NAGAMOUNIKA	13
48	16JE1A0454	PASUPULETI NAGAVASU	14
49	16JE1A0455	GODUGUNURI NARENDRA REDDY	14
50	16JE1A0457	SHAIK PARVEEN BOBBY	13
51	16JE1A0458	JAVVAJI PAVAN KUMAR	13
52	16JE1A0459	GOLLA PAVAN KUMAR	14
53	16JE1A0460	KANYADHARA PAVAN KUMAR	14
54	16JE1A0462	SHAIK RAHEEMA	12
55	16JE1A0464	SHAIK RASOOL	12
56	16JE1A0465	PATTAN RESHMA	12
57	16JE1A0467	MIRIYALA REVATHI	13
58	16JE1A0469	PUTTA ROSHINI	14
59	16JE1A0470	DHANIKONDA SAI GANGADHAR	13
60	16JE1A0471	MANIGANDLA SAI RAM	16
61	16JE1A0472	TONDEPU SAIDEEPHI	16
62	16JE1A0473	RUDRAPATI SAILAJA	13
63	16JE1A0474	NADENDLA SAILAJA	16
64	16JE1A0475	KANAMARLAPUDI SAILAKSHMI	15
65	16JE1A0476	SHAIK SAMEER MALLIK	13
66	16JE1A0477	SHAIK SHAILA BANU	13
67	16JE1A0478	BATCHU SHYAM SANKAR	14
68	16JE1A0479	PONNARSU SILPA SRI LAKSHMI	13

69	16JE1A0480	BATTULA SIVA PARVATHI	13
70	16JE1A0481	RAVULA SIVA SATYANARAYANA	13
71	16JE1A0482	YAGANTI SIVA TEJA	14
72	16JE1A0483	VIRIGINENI SIVAKALYANI	13
73	16JE1A0484	DRONADULA SIVASANKAR REDDY	13
74	16JE1A0485	AMBATI SOWJANYA	14
75	16JE1A0487	SIKHAKOLLI SRI GIRIDHARA VENKATESH	13
76	16JE1A0488	PALAPARTHI SRI KAMALA	16
77	16JE1A0489	DEVARAPU SUNEEL	15
78	16JE1A0490	GOWDAPERI SUNEETHA	14
79	16JE1A0491	SYED SUNERIA	13
80	16JE1A0492	SHAIK THOTA DARIYAVALI	14
81	16JE1A0493	TIRUMALASETTY UMA BHAVANI	13
82	16JE1A0494	KONDAPATI VAASAVI	16
83	16JE1A0495	PALLAPATI VAMSI SAI	16
84	16JE1A0496	GARLAPATI VAMSI VARDHINI	16
85	16JE1A0498	BELLAMKONDA VEERA NARAYANA	17 13
86	16JE1A0499	RAVIPATI VENKATA CHAKRADHAR	13
87	16JE1A04A0	KOTHA VENKATA KARTHIK	14
88	16JE1A04A1	YECHURI VENKATA NAGA GANGA AKHIL	13
89	16JE1A04A2	KANIGIRI VENKATA NARASIMHA AKHILA	12
90	16JE1A04A3	UPPALAPATI VENKATESH	12
91	16JE1A04A4	MAADISETTY VIJAY SANKAR	13
92	16JE1A04A5	KOMARA VIJAYA DHARANI	12
93	16JE1A04A6	KOLLA VIJAYA NAGENDRA RAO	14
94	16JE1A04A7	TUMMALACHARLA VINAY KUMAR	16
95	16JE1A04A8	TIRUMALASETTY VINEETHA	12
96	16JE1A04A9	SHAIK AYESHA	13
97	16JE1A04B0	PATTAN AYESHAA PARVEEN	14
98	16JE1A04B1	NANDAM PRAMEELA	13
99	16JE1A04B2	MANCHALA PAVANI	13
100	17JE5A0401	KAYALA K V N RAJ KUMAR	14
101	17JE5A0402	PARLAPALLI SRICHANDANA	13
102	15A45A0405	KORAMPALLI TRIVENI (Trasfer from Litam)	12


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Course Coordinator
B. BHAVANI

K. Rao
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Department of Electronics and Communication Engineering

Summary of the Program

Course Name: Microelectronics Devices

The primary objective of this 1-week value-added course is to provide students with comprehensive knowledge and practical skills in microelectronic devices. The course aims to bridge the gap between theoretical concepts and real-world applications, making students industry-ready and enhancing their career prospects in the field of Electronics and Communication Engineering. 102 (III B.Tech II Sem ECE-A and B) number of students participated.

Evaluation Criteria for Certification:

- Marks: Students were required to secure a minimum of 60% marks in the evaluation.
- Attendance: A minimum of 80% attendance was mandatory for certification.

Objective of the Course:

- To provide participants with a comprehensive understanding of the fundamental principles, operation, and applications of microelectronic devices.
- To equip participants with practical skills in analyzing and designing microelectronic circuits and systems, enhancing their ability to implement and troubleshoot electronic devices.
- To foster critical thinking and problem-solving abilities by exploring advanced topics in microelectronics, such as integrated circuits, emerging technologies, and their impact on modern electronic systems.

Course Delivery Method:


- The course consisted of lectures, and practical sessions, conducted SK Jilani Noor Basha, Assistant Professor, Department of ECE, RISE Institute of Gandhi, Ongole
- Interactive sessions encouraged active participation and engagement from the students to ensure effective learning and understanding of the concepts.


Benefits for Students:

Enhanced Skillset: Students will acquire specialized knowledge in microelectronics, equipping them with the skills required to design, analyze, and troubleshoot electronic circuits and systems.

Career Advancement: With a solid foundation in microelectronic devices and systems, students will be better positioned to pursue careers in industries such as semiconductor manufacturing, electronics design, and research and development.

Hands-on Experience: Through practical exercises and projects, students will gain valuable hands-on experience, enhancing their problem-solving, analytical, and teamwork skills.


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Innovation and Research Opportunities: The course will inspire students to explore emerging trends and technologies in microelectronics, fostering a culture of innovation and encouraging them to contribute to advancements in the field.

In conclusion, the Microelectronics Devices course offers students a comprehensive understanding of microelectronic principles and practical skills essential for modern electronic design. Through hands-on experience and exposure to emerging technologies, students are equipped to innovate and excel in diverse electronic industries. This program not only enhances students' technical proficiency but also fosters critical thinking and prepares them for rewarding careers in the rapidly evolving field of microelectronics.

Bha
(BBHAVANI)
Faculty Coordinator

K. Santhosh
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